Vishay 威世 BPW85 PDF



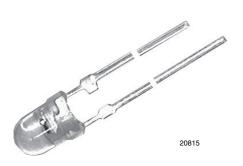
深圳创唯电子有限公司

http://www.vishay-ic.com



Vishay Semiconductors

Silicon NPN Phototransistor



DESCRIPTION

BPW85 is a silicon NPN phototransistor with high radiant sensitivity in clear, T-1 plastic package. It is sensitive to visible and near infrared radiation.

FEATURES

- · Package type: leaded
- Package form: T-1
- Dimensions (in mm): Ø 3
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\phi = \pm 25^{\circ}$
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

· Detector in electronic control and drive circuits

PRODUCT SUMMARY					
COMPONENT	I _{ca} (mA)	φ (deg)	λ _{0.1} (nm)		
BPW85	0.8 to 8	± 25	450 to 1080		
BPW85A	0.8 to 2.5	± 25	450 to 1080		
BPW85B	1.5 to 4	± 25	450 to 1080		
BPW85C	3 to 8	± 25	450 to 1080		

Note

Test condition see table "Basic Characteristics"

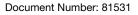
ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
BPW85	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1			
BPW85A	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1			
BPW85B	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1			
BPW85C	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1			

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Collector emitter voltage		V _{CEO}	70	V	
Emitter collector voltage		V _{ECO}	5	V	
Collector current		Ι _C	50	mA	
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA	
Power dissipation	T _{amb} ≤ 55 °C	Pv	100	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +100	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	$t \leq$ 3 s, 2 mm from case	T _{sd}	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire Ø 0.14 mm ²	R _{thJA}	450	K/W	

Rev. 2.1, 04-Aug-14





RoHS

COMPLIANT

HALOGEN

<u>GREEN</u>

(5-2008)



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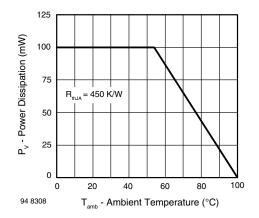


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	$I_{\rm C} = 1 \rm{mA}$	V _{(BR)CEO}	70			V
Collector emitter dark current	$V_{CE} = 20 \text{ V}, \text{ E} = 0$	I _{CEO}		1	200	nA
Collector emitter capacitance	$V_{CE} = 5 V, f = 1 MHz, E = 0$	C _{CEO}		3		pF
Angle of half sensitivity		φ		± 25		deg
Wavelength of peak sensitivity		λρ		850		nm
Range of spectral bandwidth		λ _{0.1}		450 to 1080		nm
Collector emitter saturation voltage	$\begin{array}{l} E_{e} = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \\ I_{C} = 0.1 \text{ mA} \end{array}$	V _{CEsat}			0.3	V
Turn-on time	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	t _{on}		2.0		μs
Turn-off time	V_{S} = 5 V, I_{C} = 5 mA, R_{L} = 100 Ω	t _{off}		2.3		μs
Cut-off frequency	V_S = 5 V, I_C = 5 mA, R_L = 100 Ω	f _c		180		kHz

TYPE DEDICATED CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		BPW85	I _{ca}	0.8		8.0 2.5 4.0	mA
	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$,	BPW85A	I _{ca}	0.8		2.5	mA
Collector light current	$V_{CE} = 5 V$	BPW85B	I _{ca}	1.5	8.0 2.5 4.0	4.0	mA
		BPW85C	I _{ca}	3.0		8.0	mA



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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

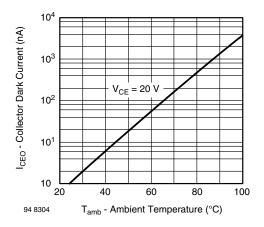


Fig. 2 - Collector Dark Current vs. Ambient Temperature

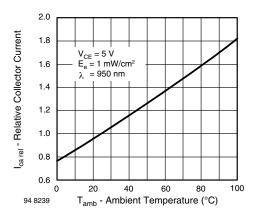


Fig. 3 - Relative Collector Current vs. Ambient Temperature

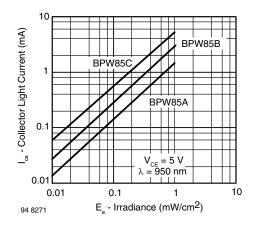


Fig. 4 - Collector Light Current vs. Irradiance

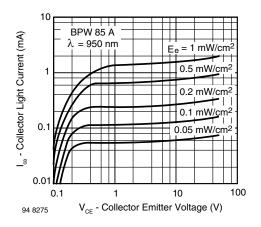


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

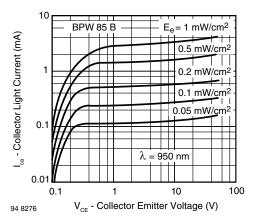


Fig. 6 - Collector Light Current vs. Collector Emitter Voltage

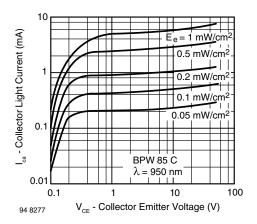


Fig. 7 - Collector Light Current vs. Collector Emitter Voltage

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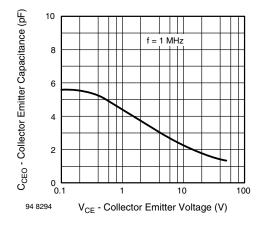


Fig. 8 - Collector Emitter Capacitance vs. Collector Emitter Voltage

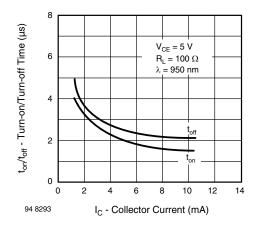


Fig. 9 - Turn-on/Turn-off Time vs. Collector Current

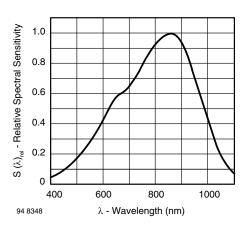


Fig. 10 - Relative Spectral Sensitivity vs. Wavelength

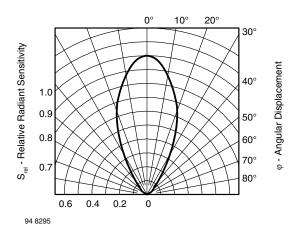
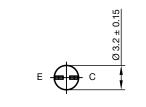


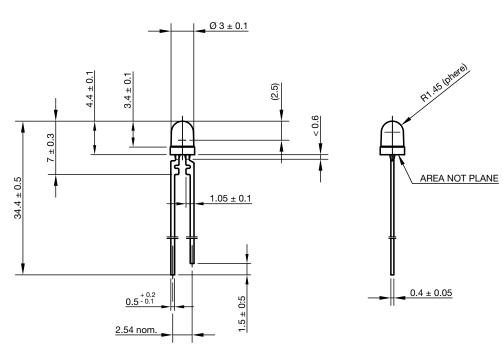
Fig. 11 - Relative Radiant Sensitivity vs. Angular Displacement



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PACKAGE DIMENSIONS in millimeters







Drawing-No.: 6.544-5054.01-4 Issue: 5; 28.07.14

technical drawings according to DIN specifications



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